# M1 THRU M7



# M1 THRU M7 Surface Mount General Purpose Silicon Rectifier

### **General description**

Surface Mount General Purpose Silicon Rectifier

#### **FEATURES**

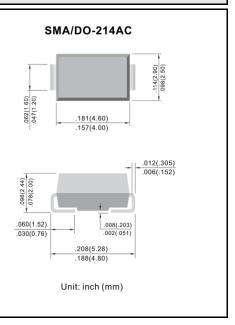
- · For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- Lead free in comply with EU RoHS 2011/65/EU directives

### **MECHANICAL DATA**

· Case: SMA

• Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.055g / 0.002oz



### Absolute Maximum Ratings(Ta=25°C unless otherwise specified)

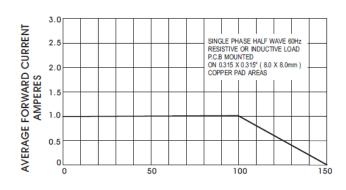
Parameter	Symbols	M1	M2	МЗ	M4	M5	M6	M7	Units
Marking Code	Mark	M1	M2	МЗ	M4	M5	M6	M7	N/A
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current	<b>I</b> F(AV)	1					А		
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	Ігѕм	30					Α		
Maximum Instantaneous Forward Voltage at 1 A	V <sub>F</sub>	1.1					V		
	I <sub>R</sub>	5 50					μA		
Maximum Reverse Recovery Time(Note 1) TJ=25°C	Trr	2					uS		
Typical Junction Capacitance (Note 2)	Cj	12					pF		
Maximum Thermal Resistance(Note 3) RθJA	Reja	30				°C/W			
Operating and Storage Temperature Range	Tj, Tstg	-55 ~ +150					°C		

NOTES: 1. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, Irr=0.25A

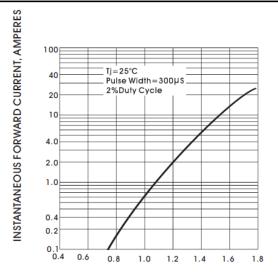
2. Measured at 1 MHz and applied Vr = 4.0 volts.



### **Typical Characteristics**



TEMPERATURE°C
Fig. 1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT



INSTANTANEOUS FORWARD VOLTAGE, VOLTS
Fig. 2- TYPICAL INSTANTANEOUS FORWARD
CHARACTERISITCS PER ELEMENT

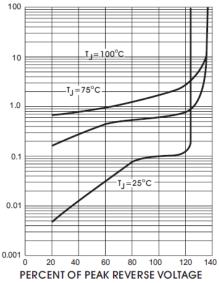


Fig. 3- TYPICAL REAK REVERSE CHARACTERISTICS

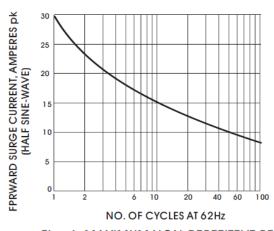
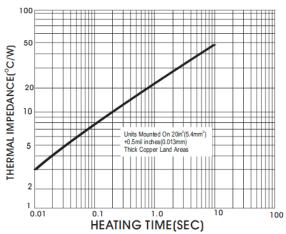


Fig. 4- MAXIMUM NON-REPETITEVE PEAK FORWARD SURGE CURRENT





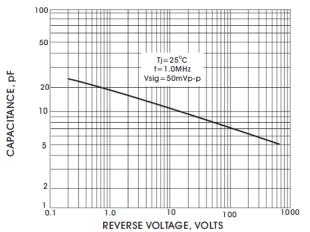
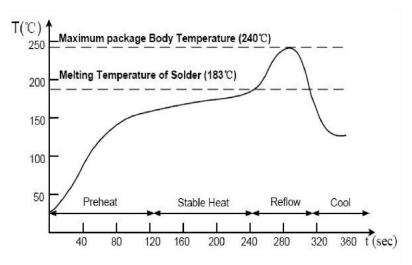


Fig. 6-TYPICL JUNCTION CAPACITANCE PER ELEMENT

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## **Suggested Soldering Temperature Profile**

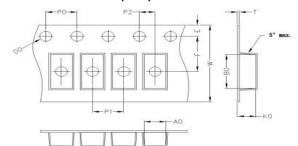


#### Note

- Recommended reflow methods: IR, vapor phase oven, hot air oven, wave solder.
- → The device can be exposed to a maximum temperature of 265°C for 10 seconds.
- → Devices can be cleaned using standard industry methods and solvents.
- → If reflow temperatures exceed the recommended profile, devices may not meet the performance requirements.

### **Package Information**

### Carrier Dimension(mm)



A0	В0	K0	D0	E	F	
2.80	5.30	2.36	1.55	1.75	5.50	
P0	P1	P2	Т	W	Tolerance	

### **Package Specifications**

Package	Reel Size	Reel DIA. (mm)	Q'TY/Reel (Kpcs)	Box Size (mm)	QTY/Box (Kpcs)	Carton Size (mm)	Q'TY/Carton (Kpcs)
SMA	7'	178	2	180*180*73	8	380*200*200	80
	11'	280	5	288*288*38	10	355*310*310	80



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